Product data sheet

1. General description

EEPP[™]- Efficiency Enhanced Pt Planar diode in a SOD142 (2-leads TO247) plastic package.

2. Features and benefits

- Fast switching
- · Reduces switching losses with improved lower reverse recovery charge
- · Soft recovery characteristics
- · Low thermal resistance
- Low leakage current
- High operating temperature capability (T_{j (max)} = 175°C)
- Higher I_{FSM} capability
- Planar termination structure

3. Applications

- · Switched-Mode Power Supplies
- Power factor correction diode
- Uninterrupted Power Supply

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Va	lues		Unit
Absolute	maximum rating						
V_{RRM}	repetitive peak reverse voltage			1200			V
I _{F(AV)}	average forward current	$δ = 0.5$; square-wave pulse; $T_{mb} \le 95$ °C; Fig. 1; Fig. 2; Fig. 3		;	30		А
I _{FRM}	repetitive peak forward current	δ = 0.5 ; t_p = 25 μ s; $T_{mb} \le 95$ °C; square-wave pulse		(60		А
I _{FSM}	non-repetitive peak forward current	t_p = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; Fig. 4	270			А	
		t_p = 8.3 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse;		3	800		Α
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Static ch	aracteristics						
V _F	forward voltage	I _F = 30 A; T _j = 25 °C; <u>Fig. 6</u>		-	2.7	3.3	V
		I _F = 30 A; T _j = 150 °C; <u>Fig. 6</u>		-	2.1	-	V
Dynamic	characteristics						
t _{rr} reverse recovery time		$I_F = 1 \text{ A}; V_R = 30 \text{ V}; dI_F/dt = 100 \text{ A/}\mu\text{s};$ $T_j = 25 \text{ °C}; Fig. 7$		-	-	65	ns
		$I_F = 30 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 500 \text{ A/}\mu\text{s};$ $T_j = 25 \text{ °C}; Fig. 7$		-	70	-	ns
		$I_F = 30 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 500 \text{ A/}\mu\text{s};$ $T_j = 125 \text{ °C}; Fig. 7$		-	153	-	ns
		$I_F = 30 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 500 \text{ A/}\mu\text{s};$ $T_j = 150 \text{ °C}; Fig. 7$		-	173	-	ns
Avalanch	e energy						
E _{AS}	non-repetitive avalanche energy	T _{j(init)} = 25 °C		30	-	-	mJ

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	K	cathode	000	K — A 001aaa020
2	Α	anode	рОц	001aaa020
mb	mb	mounting base; connected to cathod	K A TO-247 (SOD142)	

6. Ordering information

Table 3. Ordering information

Type number	Package	9				
	Name	Description	Version			
BYC30W-1200P	TO-247	plastic single-ended through-hole package; heatsink mounted; 1 mounting hole; 2-leads TO-247	SOD142			

7. Marking

Table 4. Marking codes

Type number	Marking codes
BYC30W-1200P	BYC30W-1200P

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Values	Unit
V_{RRM}	repetitive peak reverse voltage		1200	V
V_{RWM}	crest working reverse voltage		1200	V
V_R	reverse voltage	DC	1200	V
I _{F(AV)}	average forward current	$δ = 0.5$; square-wave pulse; $T_{mb} \le 95$ °C; Fig. 1; Fig. 2; Fig. 3	30	А
I _{FRM}	repetitive peak forward current	δ = 0.5 ; t _p = 25 μs; T _{mb} ≤ 95 °C; square-wave pulse	60	А
I _{FSM}	non-repetitive peak forward current	t_p = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; Fig. 4	270	Α
		t_p = 8.3 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse;	300	Α
T _{stg}	storage temperature		-65 to 175	°C
T _j	junction temperature		175	°C

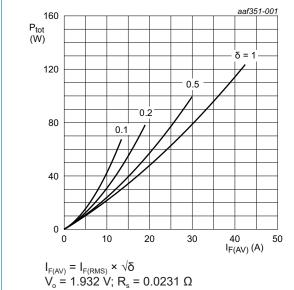
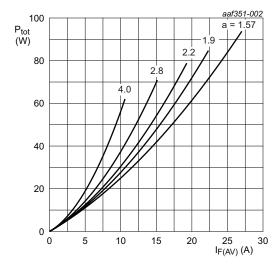
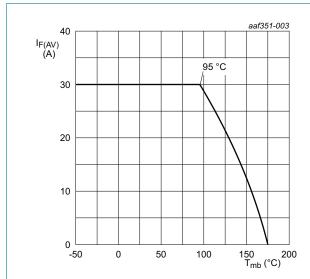


Fig. 1. Forward power dissipation as a function of average forward current; square waveform; maximum values



a = form factor = $I_{F(RMS)}/I_{F(AV)}$ Vo = 1.932 V; Rs = 0.0231 Ω

Fig. 2. Forward power dissipation as a function of average forward current; sinusoidal waveform; maximum values





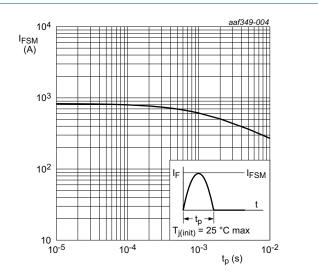


Fig. 4. Non-repetitive peak forward current as a function of pulse width; sinusoidal waveform; maximum values

9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-mb)}	thermal resistance from junction to mounting base	Fig. 5	-	-	0.8	K/W
$R_{\text{th(j-a)}}$	thermal resistance from junction to ambient free air	in free air	-	45	-	K/W

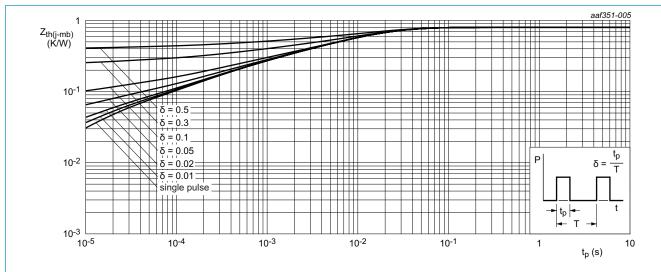
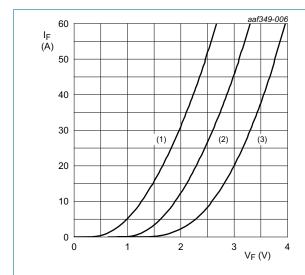


Fig. 5. Transient thermal impedance from junction to mounting base as a function of pulse duration

10. Characteristics

Table 7. Characteristics

Symbo	I Parameter	Conditions	Min	Тур	Max	Unit
Static o	characteristics					
V_{F}	forward current	I _F = 30 A; T _j = 25 °C; <u>Fig. 6</u>	-	2.7	3.3	V
		I _F = 30 A; T _j = 150 °C; <u>Fig. 6</u>	-	2.1	-	V
I _R	reverse current	V _R = 1200 V; T _j = 25 °C	-	-	250	μA
		V _R = 1200 V; T _j = 150 °C	-	-	1	mA
Dynam	ic characteristics					
Q _r	reverse charge	$I_F = 30 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 500 \text{ A/µs};$ $T_j = 25 \text{ °C}; Fig. 7$	-	572	-	nC
		$I_F = 30 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 500 \text{ A/}\mu\text{s};$ $T_j = 125 \text{ °C}; Fig. 7$	-	1573	-	nC
		$I_F = 30 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 500 \text{ A/}\mu\text{s};$ $T_j = 150 \text{ °C}; Fig. 7$	-	1940	-	nC
t _{rr}	reverse recovery time	$I_F = 1 \text{ A}; V_R = 30 \text{ V}; dI_F/dt = 100 \text{ A/µs};$ $T_j = 25 ^{\circ}\text{C}; Fig. 7$	-	-	65	ns
		$I_F = 30 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 500 \text{ A/µs};$ $T_j = 25 \text{ °C}; Fig. 7$	-	70	-	ns
		I _F = 30 A; V _R = 400 V; dI _F /dt = 500 A/µs; T _j = 125 °C; <u>Fig. 7</u>	-	153	-	ns
		I _F = 30 A; V _R = 400 V; dI _F /dt = 500 A/μs; T _i = 150 °C; <u>Fig. 7</u>	-	173	-	ns
I _{RM}	peak reverse recovery current	I _F = 30 A; V _R = 400 V; dI _F /dt = 500 A/μs; T _i = 25 °C; <u>Fig. 7</u>	-	16	-	А
		I _F = 30 A; V _R = 400 V; dI _F /dt = 500 A/μs; T _i = 125 °C; <u>Fig. 7</u>	-	21	-	А
		I _F = 30 A; V _R = 400 V; dI _F /dt = 500 A/μs; T _j = 150 °C; <u>Fig. 7</u>	-	22	-	А
Avalan	che energy			•		
E _{AS}	non-repetitive avalanche energy	T _{j(init)} = 25 °C	30	-	-	mJ



 V_o = 1.932 V; R_s = 0.0231 Ω

(1) $T_j = 150 \,^{\circ}\text{C}$; typical values

(2) $T_i = 150 \,^{\circ}\text{C}$; maximum values

(3) $T_j = 25$ °C; maximum values

Fig. 6. Forward current as a function of forward voltage

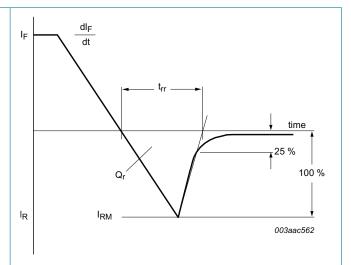
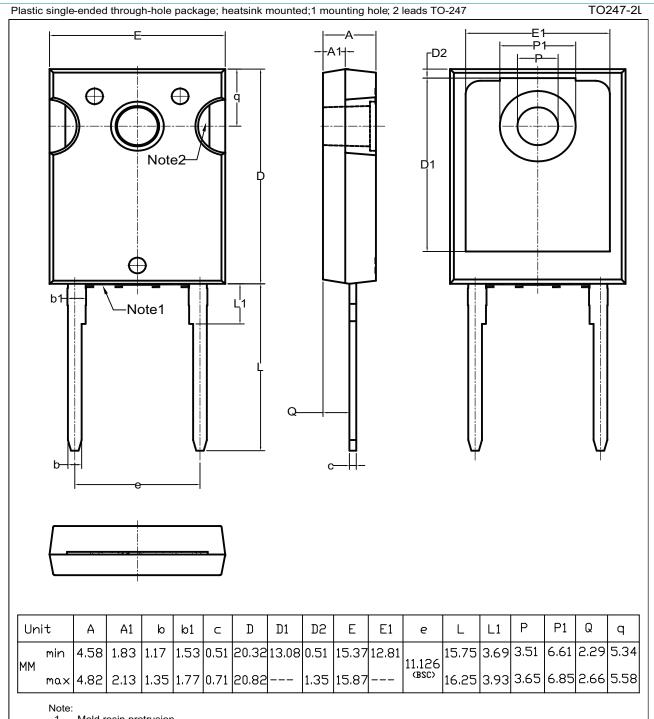


Fig. 7. Reverse recovery definitions; ramp recovery

11. Package outline



- Mold resin protrusion.
- 2. Metal exposed with Sn plating.

Fig. 8. Package outline SOD142 (TO247)

12. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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